M1MA141WAT1, M1MA142WAT1

Preferred Device

Common Anode Silicon Dual Switching Diode

This Common Anode Silicon Epitaxial Planar Dual Diode is designed for use in ultra high speed switching applications. This device is housed in the SC-70 package which is designed for low power surface mount applications.

Features

- Fast t_{rr} , < 10 ns
- Low C_D, < 15 pF
- Pb–Free Package is Available

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating		Symbol	Value	Unit
Reverse Voltage	M1MA141WAT1 M1MA142WAT1	V _R	40 80	Vdc
Peak Reverse Voltage	M1MA141WAT1 M1MA142WAT1	V _{RM}	40 80	Vdc
Forward Current	Single Dual	Ι _F	100 150	mAdc
Peak Forward Current	Single Dual	I _{FM}	225 340	mAdc
Peak Forward Surge Current M1MA141WAT1 M1MA142WAT1		I _{FSM} (Note 1)	500 750	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	PD	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T _{stg}	-55 ~ +150	°C

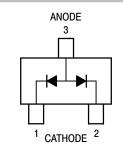
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

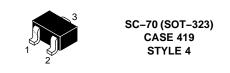
1. t = 1 sec



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MARKING DIAGRAM



Mx = Device Codex = N for 141O for 142

M = Date Code*

= Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
M1MA141WAT1	SC-70	3000/Tape & Reel
M1MA141WAT1G	SC-70 (Pb-Free)	3000/Tape & Reel
M1MA142WAT1	SC-70	3000/Tape & Reel
M1MA142WAT1G	SC-70 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

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ELECTRICAL CHARACTERISTICS (T_A = 25° C)

Characteristic	Condition	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current M1MA141WAT1 M1MA142WAT1	V _R = 35 V V _R = 75 V	I _R	-	0.1	μAdc
Forward Voltage	I _F = 100 mA	V _F	-	1.2	Vdc
Reverse Breakdown Voltage M1MA141WAT1 M1MA142WAT1	I _R = 100 μA	V _R	40 80	-	Vdc
Diode Capacitance	V _R = 0, f = 1.0 MHz	CD	-	15	pF
Reverse Recovery Time (Figure 1)	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V}, R_L = 100 \Omega, I_{rr} = 0.1 I_R$	t _{rr} (Note 2)	-	10	ns

2. t_{rr} Test Circuit

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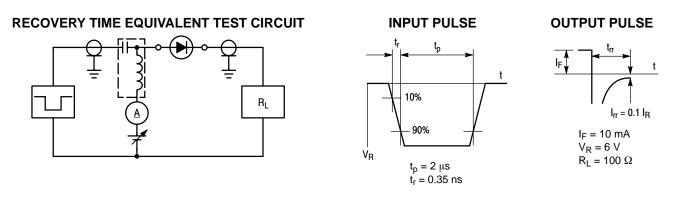
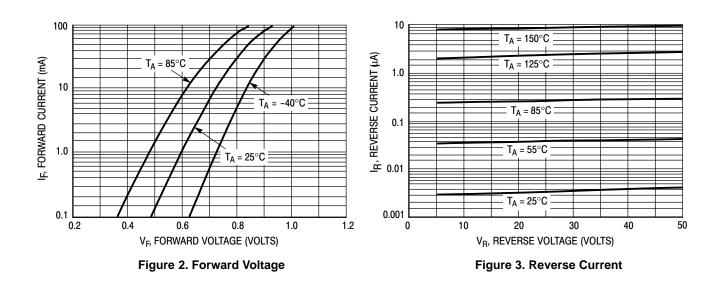
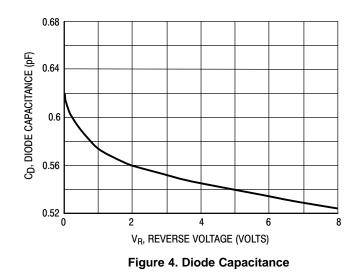


Figure 1. Recovery Time Equivalent Test Circuit

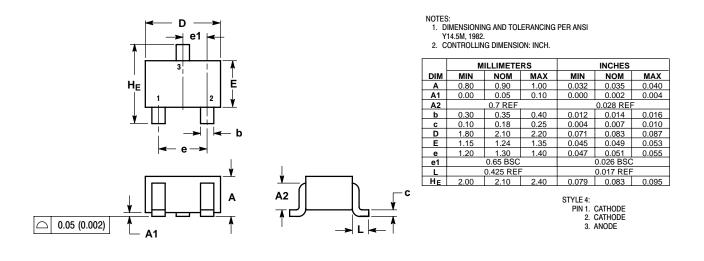




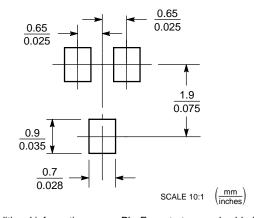
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PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE M



SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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